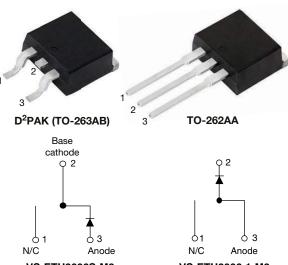
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# VS-ETU3006S-M3, VS-ETU3006-1-M3

**Vishay Semiconductors** 

# Ultrafast Rectifier, 30 A FRED Pt<sup>®</sup>



VS-ETU3006S-M3

VS-ETU3006-1-M3

PRIMARY CHARACTERISTICS								
I <sub>F(AV)</sub> 30 A								
V <sub>R</sub>	600 V							
V <sub>F</sub> at I <sub>F</sub>	1.15 V							
t <sub>rr</sub> (typ.)	30 ns							
T <sub>J</sub> max.	175 °C							
Package	D <sup>2</sup> PAK (TO-263AB), TO-262AA							
Circuit configuration	Single							

#### **FEATURES**

- Low forward voltage drop
- · Ultrafast recovery time
- 175 °C operating junction temperature
- · Low leakage current
- Designed and gualified according to JEDEC<sup>®</sup>-JESD 47
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### DESCRIPTION

Ultralow V<sub>F</sub>, soft-switching ultrafast rectifiers optimized for discontinuous (Critical) mode (DCM) power factor correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimized the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

### **APPLICATIONS**

AC/DC SMPS 70 W to 400 W

e.g. laptop and printer AC adaptors, desktop PC, TV and monitor, games units, and DVD AC/DC power supplies.

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS				
Repetitive peak reverse voltage	V <sub>RRM</sub>		600	V				
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 113 °C	30	٨				
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>C</sub> = 25 °C	200	A				
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C				

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-			
	V	I <sub>F</sub> = 30 A	-	1.4	2.0	V		
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	-	1.15	1.35			
		$V_{\rm R} = V_{\rm R}$ rated	-	0.02	30			
Reverse leakage current	IR	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	30	250	μA		
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	20	-	pF		
Series inductance	LS	Measured lead to lead 5 mm from package body	-	8.0	-	nH		

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A}$	õs, V <sub>R</sub> = 30 V	-	30	45		
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 30 A dI <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 200 V	-	45	-	ns	
		T <sub>J</sub> = 125 °C		-	100	-		
Book receivers ourrent	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	5.6	-	А	
Peak recovery current		T <sub>J</sub> = 125 °C		-	10	-	A	
	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	127	-	-	
Reverse recovery charge		T <sub>J</sub> = 125 °C		-	580	-	nC	

THERMAL - MECHANIC	THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C			
Thermal resistance, junction to case	R <sub>thJC</sub>		-	0.95	1.4	°C/W			
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	70				
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.5	-				
Weight			-	2.0	-	g			
Weight			-	0.07	-	oz.			
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)			
Marking device		Case style D <sup>2</sup> PAK (TO-263AB)		ETUS	3006S				
		Case style TO-262		ETU3	006-1				

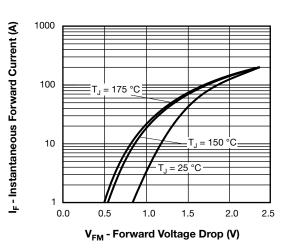
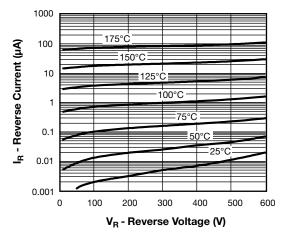
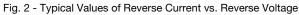


Fig. 1 - Typical Forward Voltage Drop Characteristics





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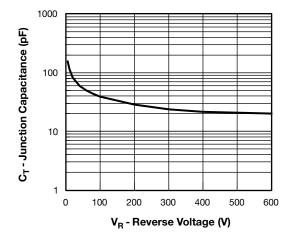


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

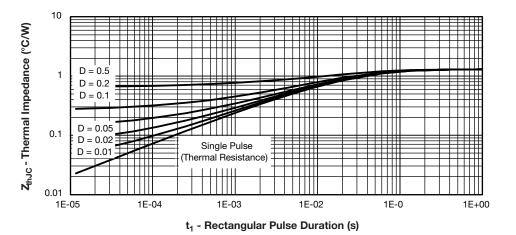


Fig. 4 - Max. Thermal Impedance Z<sub>thJC</sub> Characteristics

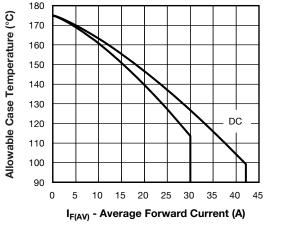


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

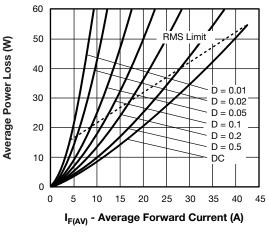


Fig. 6 - Forward Power Loss Characteristics

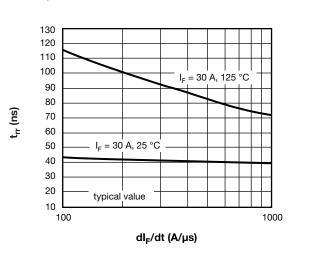
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Fig. 7 - Typical Reverse Recovery vs. dl<sub>F</sub>/dt

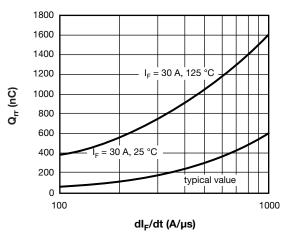


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

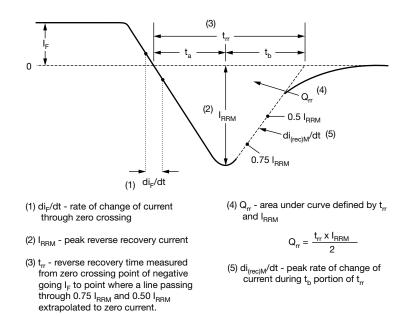


Fig. 9 - Reverse Recovery Waveform and Definitions



### **ORDERING INFORMATION TABLE**

Device code	VS-	Е	т	U	30	06	S	TRL	-M3	
		2	3	4	5	6	7	8	9	
	1 -	Visl	nay Sem	niconduc	ctors pro	oduct				
	2 -		uit conf	iguratior	ı					
	3 -		TO-220							
	4 -	U =	ultrafas	t recove	ry time					
	5 -	Cur	rent coc	le (30 =	30 A)					
	6 -	Volt	tage coo	le (06 =	600 V)					
	7 -	• S	= D <sup>2</sup> PA	K (TO-2	63AB)					
	-	• -1	= TO-2	62AA						
	8 -	• No	one = tu	be (50 p	ieces)					
	-	• TF	RL = tap	e and re	el (left o	oriented	l, for D <sup>2</sup>	PAK (T	O-263A	B) package
	-	• TF	RR = tap	e and re	el (righ	t oriente	ed, for [	D <sup>2</sup> PAK	(TO-263	3AB) packag
	9 -	-M3	s = halog	gen-free	, RoHS-	complia	ant and	termina	ations le	ad (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION						
VS-ETU3006S-M3	50	Antistatic plastic tubes						
VS-ETU3006STRR-M3	800	13" diameter plastic tape and reel						
VS-ETU3006STRL-M3	800	13" diameter plastic tape and reel						
VS-ETU3006-1-M3	50	Antistatic plastic tubes						

	LINKS TO RELATED DOCUMENTS								
Dimonoiono	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?96164							
Dimensions	TO-262AA	www.vishay.com/doc?96165							
Ded and the information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?95444							
Part marking information	TO-262AA	www.vishay.com/doc?95443							
Packaging information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?96424							
SPICE model		www.vishay.com/doc?96775							



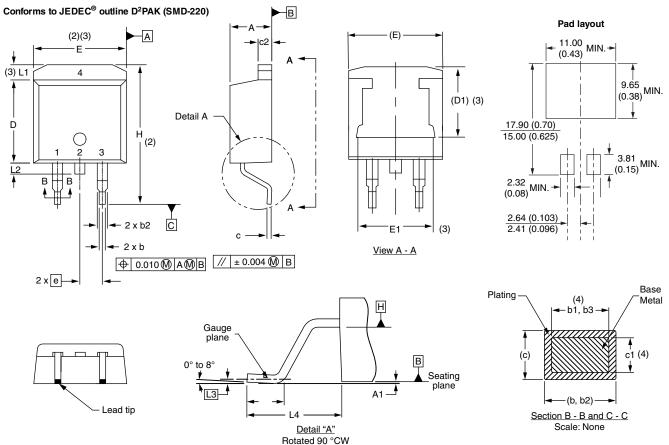
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D<sup>2</sup>PAK

#### **DIMENSIONS** in millimeters and inches

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SYMBOL	MILLIM	MILLIMETERS		HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
A	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STNIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	2.54 BSC		) BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25	BSC	0.010	BSC	
L4	4.78	5.28	0.188	0.208	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Datum A and B to be determined at datum plane H

<sup>(6)</sup> Controlling dimension: inches

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

Revision: 13-Jul-17

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Document Number: 96164

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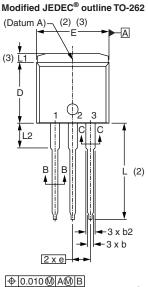
### **Outline Dimensions**

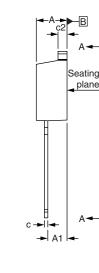


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**TO-262AA** 

#### **DIMENSIONS** in millimeters and inches



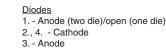


D1 (3) (3) Section A - A Base (4) Plating b1. b3 metal ≰ c1 (4) -(b, b2)-Section B - B and C - C Scale: None

E

010	(M) A	.@/E	3		
_				_	
	math	math.	mark		





Lead assignments

SYMBOL	MILLIN	METERS	INC	INCHES		
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
E	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54	BSC	0.100	) BSC		
L	13.46	14.10	0.530	0.555		
L1	-	1.65	-	0.065	3	
L2	3.56	3.71	0.140	0.146		

#### Notes

 <sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the second flash include mold flash. the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches

(6) Outline conform to JEDEC® TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), L1 (max.), L2 (min., max.)

Revision: 30-Nov-17

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